



# DDR SDRAM DIMM MODULE, 2.5V 256MByte - 32MX64 AVM6432U51C5266K3-AP

## FEATURES

JEDEC DDR 266MHz PC2100, Lead-Free, RoHS compliant

- Clock frequency: 133MHz with CAS latency 2.5
- 256 byte serial EEPROM
- Data input and output masking
- Programmable burst length: 2, 4, 8
- Programmable burst type: sequential and interleave
- Programmable CAS latency: 2.5
- Auto refresh and self refresh capability
- Gold card edge fingers
- 8K refresh per 64ms
- Low active and standby current consumption
- SSTL-2 compatible inputs and outputs
- Decoupling capacitors at each memory device
- Single-sided module
- 29.46mm (1.16) inch height

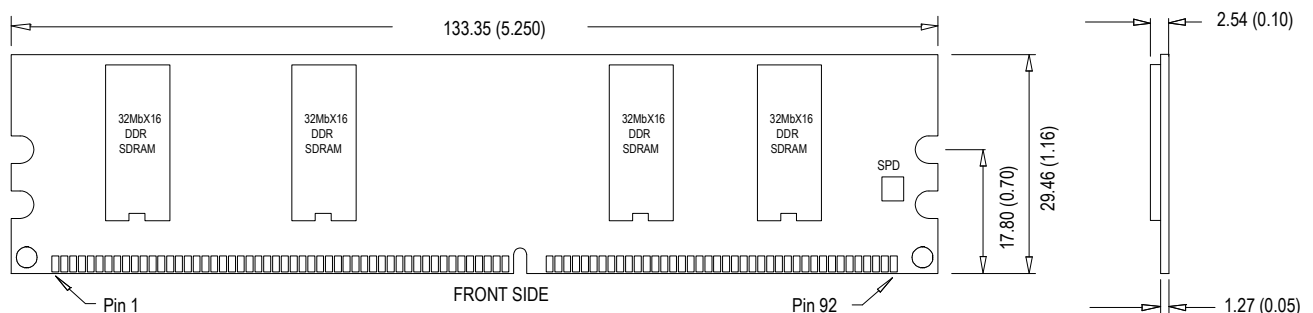
## DESCRIPTION

The AVM6432U51C5266K3-AP is a 184 pin Unbuffered DDR SDRAM DIMM module. This module is JEDEC pinout compatible. A 256 byte serial EEPROM on board can be used to store module information such as timing, configuration, density, etc.

The AVM6432U51C5266K3-AP memory module is 256MByte and organized as 32MX64 array using (4) 32MX16 DDR SDRAMs in TSSOP II packages.

This memory module is fabricated using the latest technology design, six-layer printed circuit board substrate construction with low ESR decoupling capacitors on-board for high reliability and low noise.

## PHYSICAL DIMENSIONS



- NOTES: 1- All dimensions are in millimeters (inches)  
2- The dimensional drawings are for reference only. Refer to the JEDEC document for additional information.

**Avant Ordering Guides**

<b>AV</b>	<b>M</b>	<b>64</b>	<b>32</b>	<b>U</b>	<b>51</b>	<b>C</b>	<b>5</b>	<b>266</b>	<b>K</b>	<b>3</b>
INVENTORY	MOD. TYPE	ORG.	DENSITY	PARITY	TYPE	VOLTAGE	FEATURE	SPEED	MODE	REV
AV = AVANT	M=184-PIN DDR DIMM	64=X64	32 = 32M	U=UNBUFFERED	51 = 8Mx16x4 (DDR SDRAM)	C = 2.5V	5 = CAS LATENCY 2.5	266MHz	K = DDR	REV=3

Other options may be available. Call for specific part number information on options not listed.



Avant™ Technology LP., reserves the right to change products or specifications without notice.